SGR6N60UF

FAIRCHILD SEMICONDUCTOR®

IGBT

SGR6N60UF

Ultra-Fast IGBT

General Description

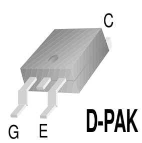
Fairchild's UF series of Insulated Gate Bipolar Transistors (IGBTs) provides low conduction and switching losses. The UF series is designed for applications such as motor control and general inverters where high speed switching is a required feature.

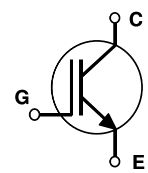
Features

- High speed switching
- Low saturation voltage : $V_{CE(sat)}$ = 2.1 V @ I_C = 3A
- High input impedance

Applications

AC & DC motor controls, general purpose inverters, robotics, and servo controls.





Absolute Maximum Ratings

T_C = 25°C unless otherwise noted

Symbol	Description		SGR6N60UF	Units
V_{CES}	Collector-Emitter Voltage		600	V
V_{GES}	Gate-Emitter Voltage		± 20	V
I_C	Collector Current	@ T_C = 25°C	6	A
	Collector Current	@ T_C = 100°C	3	A
$I_{CM\ (1)}$	Pulsed Collector Current		25	A
P_D	Maximum Power Dissipation	@ T_C = 25°C	30	W
	Maximum Power Dissipation	@ T_C = 100°C	12	W
T_J	Operating Junction Temperature		-55 to +150	°C
T_{stg}	Storage Temperature Range		-55 to +150	°C
T_L	Maximum Lead Temp. for Soldering Purposes, 1/8” from Case for 5 Seconds		300	°C

Notes :
(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	--	4.0	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (PCB Mount) (2)	--	50	°C/W

Notes :
(2) Mounted on 1” squre PCB (FR4 or G-10 Material)

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
BV_{CES}	Collector-Emitter Breakdown Voltage	V_{GE} = 0V, I_C = 250uA	600	--	--	V
$\Delta B_{VCES}/\Delta T_J$	Temperature Coefficient of Breakdown Voltage	V_{GE} = 0V, I_C = 1mA	--	0.6	--	V/°C
I_{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}$, V_{GE} = 0V	--	--	250	uA
I_{GES}	G-E Leakage Current	$V_{GE} = V_{GES}$, V_{CE} = 0V	--	--	± 100	nA
On Characteristics						
$V_{GE(th)}$	G-E Threshold Voltage	I_C = 3mA, $V_{CE} = V_{GE}$	3.5	4.5	6.5	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	I_C = 3A, V_{GE} = 15V	--	2.1	2.6	V
		I_C = 6A, V_{GE} = 15V	--	2.6	--	V
Dynamic Characteristics						
C_{ies}	Input Capacitance	V_{CE} = 30V, V_{GE} = 0V, f = 1MHz	--	220	--	pF
C_{oes}	Output Capacitance		--	22	--	pF
C_{res}	Reverse Transfer Capacitance		--	7	--	pF
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{CC} = 300 V, I_C = 3A, R_G = 80Ω, V_{GE} = 15V, Inductive Load, T_C = 25°C	--	15	--	ns
t_r	Rise Time		--	25	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	60	130	ns
t_f	Fall Time		--	70	150	ns
E_{on}	Turn-On Switching Loss		--	57	--	uJ
E_{off}	Turn-Off Switching Loss		--	25	--	uJ
E_{ts}	Total Switching Loss		--	82	120	uJ
$t_{d(on)}$	Turn-On Delay Time	V_{CC} = 300 V, I_C = 3A, R_G = 80Ω, V_{GE} = 15V, Inductive Load, T_C = 125°C	--	22	--	ns
t_r	Rise Time		--	32	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	80	200	ns
t_f	Fall Time		--	122	300	ns
E_{on}	Turn-On Switching Loss		--	65	--	uJ
E_{off}	Turn-Off Switching Loss		--	46	--	uJ
E_{ts}	Total Switching Loss		--	111	170	uJ
Q_g	Total Gate Charge	V_{CE} = 300 V, I_C = 3A, V_{GE} = 15V	--	15	22	nC
Q_{ge}	Gate-Emitter Charge		--	5	8	nC
Q_{gc}	Gate-Collector Charge		--	4	6	nC
L_e	Internal Emitter Inductance	Measured 5mm from PKG	--	7.5	--	nH

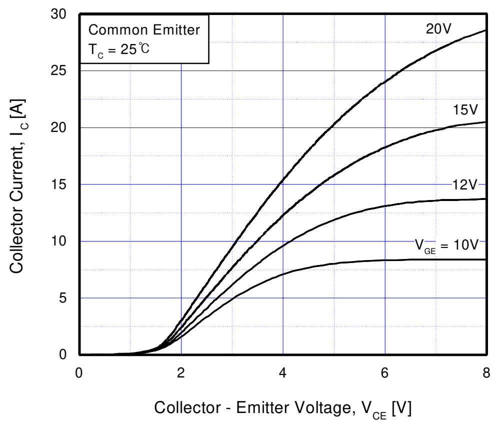


Fig 1. Typical Output Characteristics

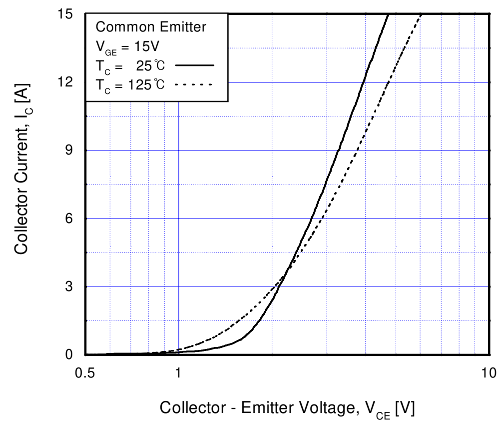


Fig 2. Typical Saturation Voltage Characteristics

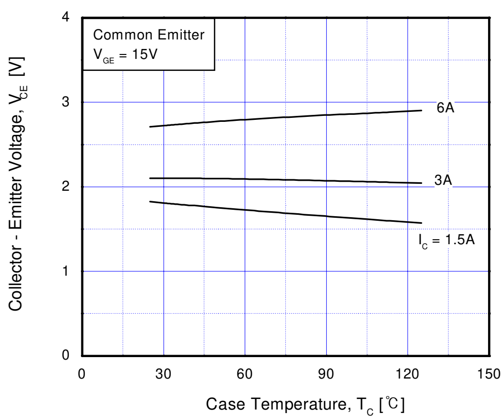


Fig 3. Saturation Voltage vs. Case Temperature at Variant Current Level

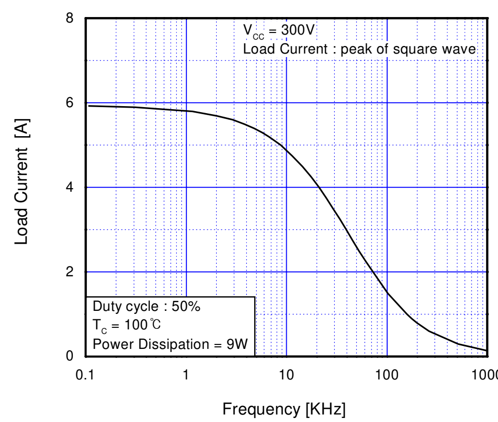


Fig 4. Load Current vs. Frequency

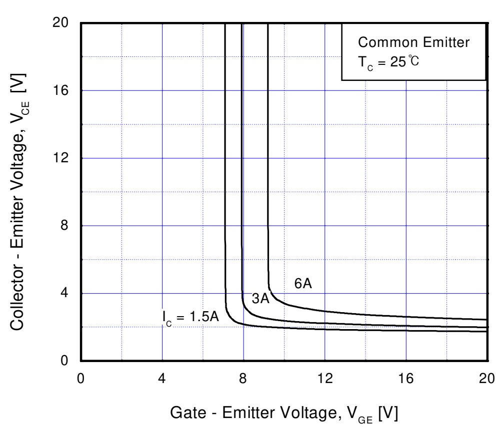


Fig 5. Saturation Voltage vs. V_{GE}

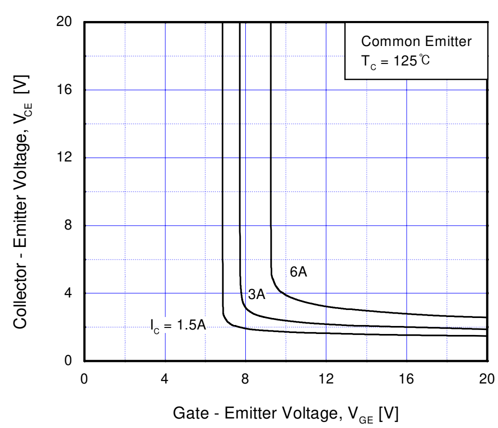


Fig 6. Saturation Voltage vs. V_{GE}

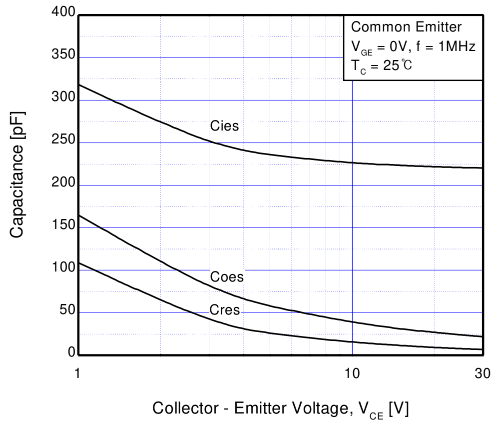


Fig 7. Capacitance Characteristics

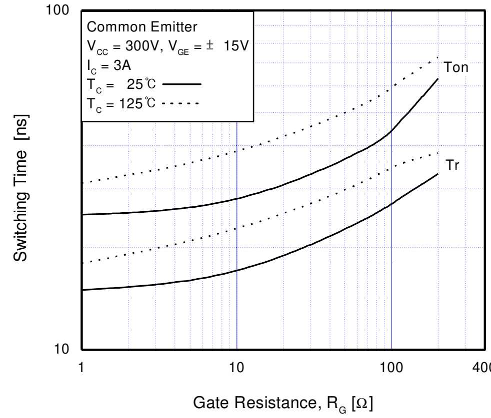


Fig 8. Turn-On Characteristics vs. Gate Resistance

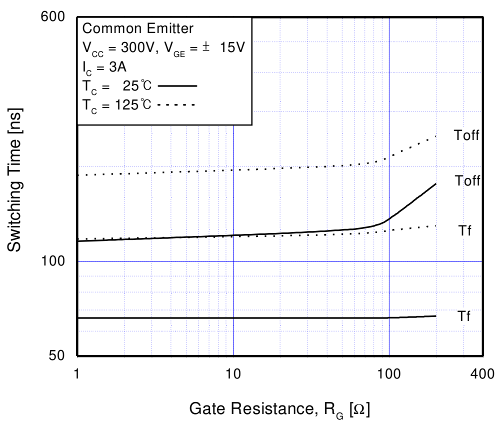


Fig 9. Turn-Off Characteristics vs. Gate Resistance

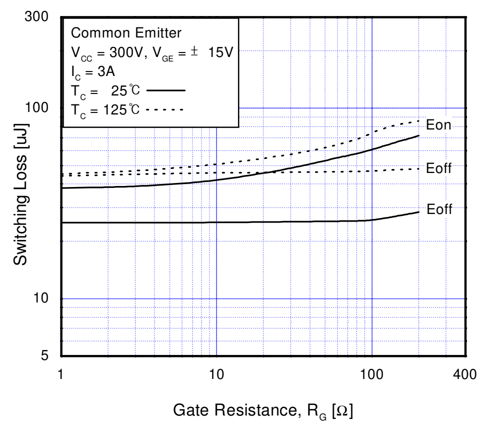


Fig 10. Switching Loss vs. Gate Resistance

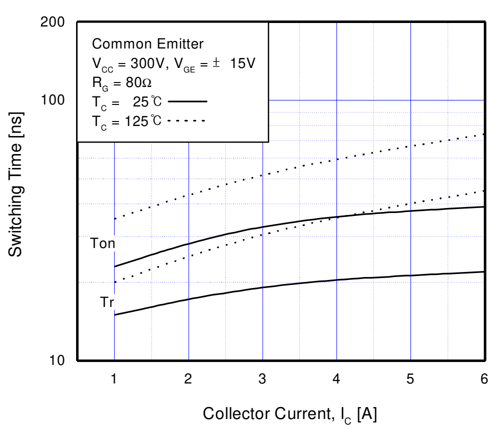


Fig 11. Turn-On Characteristics vs. Collector Current

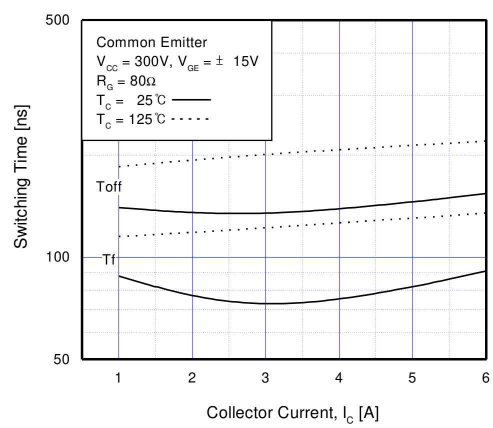


Fig 12. Turn-Off Characteristics vs. Collector Current

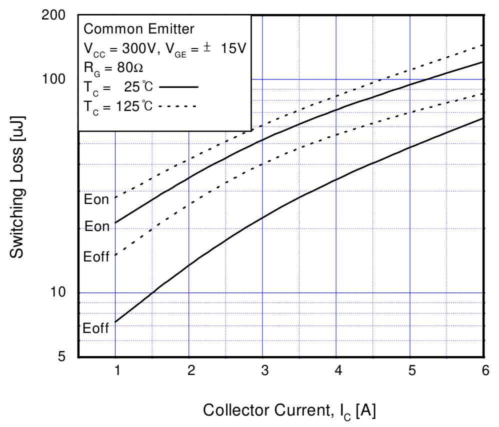


Fig 13. Switching Loss vs. Collector Current

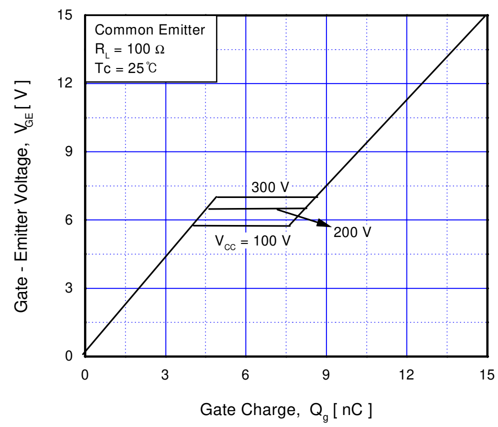


Fig 14. Gate Charge Characteristics

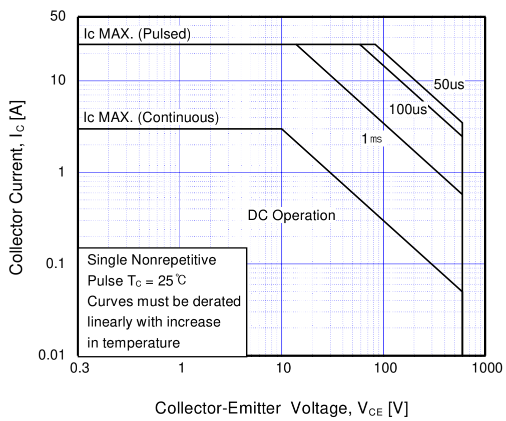


Fig 15. SOA Characteristics

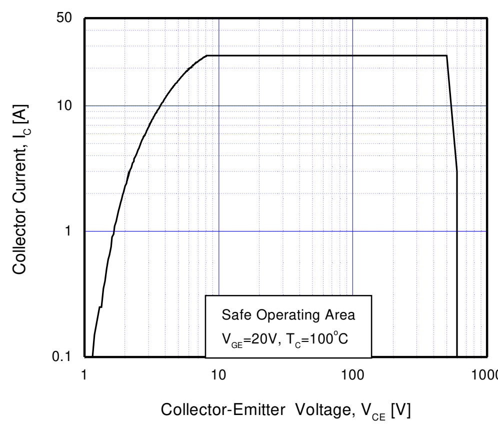


Fig 16. Turn-Off SOA Characteristics

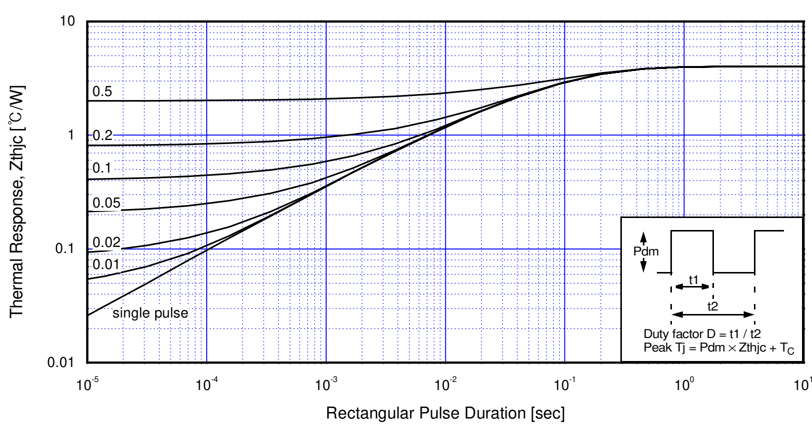
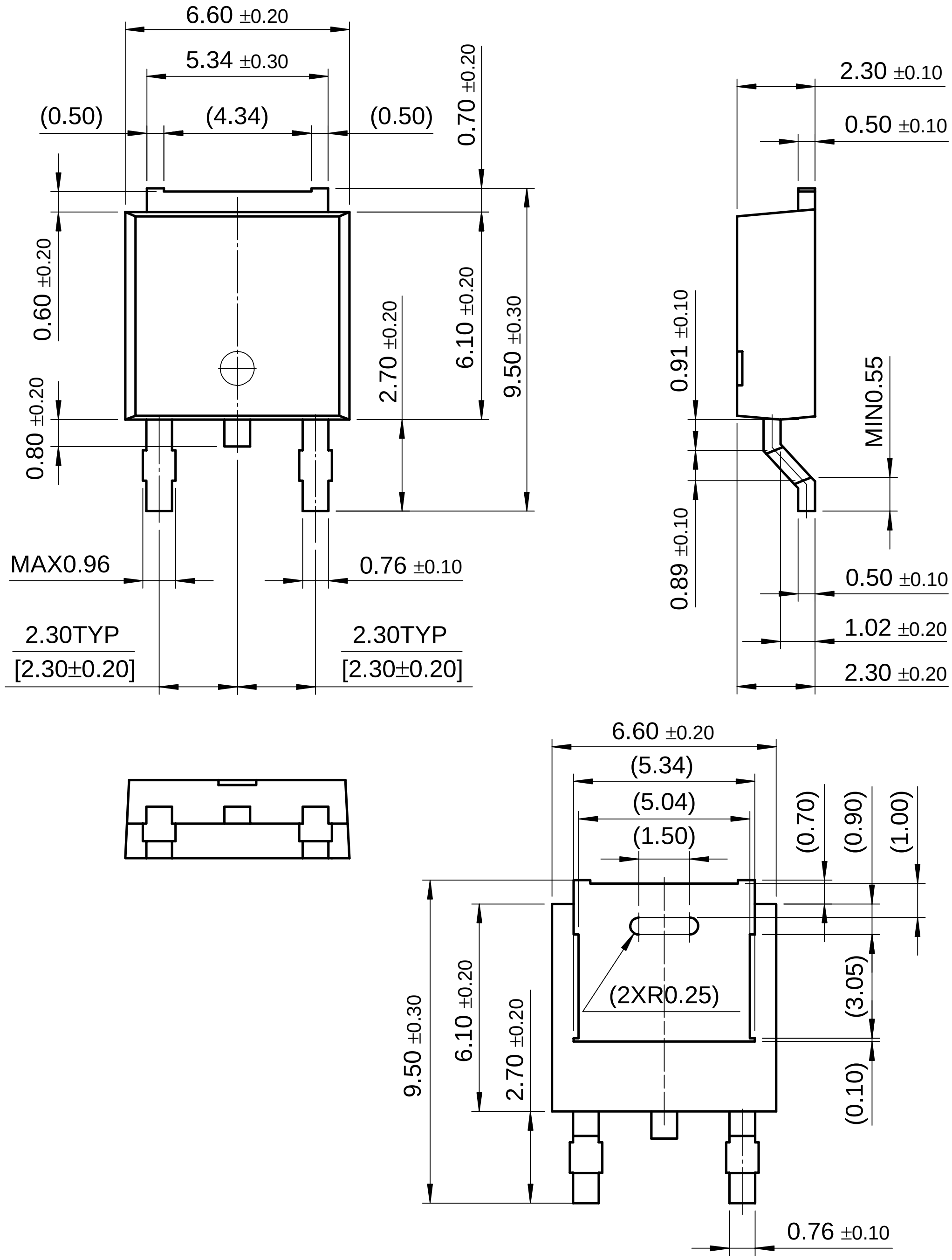


Fig 17. Transient Thermal Impedance of IGBT

Package Dimension

D-PAK



Dimensions in Millimeters

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

SGR6N60UF
Discrete, High Performance IGBT

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General description

Fairchild's UF series of Insulated Gate Bipolar Transistors (IGBTs) provides low conduction and switching losses. The UF series is designed for applications such as motor control and general inverters where high speed switching is a required feature.

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Features

- High Speed Switching
- Low Saturation Voltage : $V_{CE(sat)} = 2.1$ V @ $I_C = 3$A
- High Input Impedance

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Applications

AC &DC Motor controls, General Purpose Inverters, Robotics, Servo Controls

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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method

SGR6N60UFTF	Full Production	$0.59	TO-252(DPAK)	2	TAPE REEL
SGR6N60UFTM	Full Production	$0.59	TO-252(DPAK)	2	TAPE REEL

* 1,000 piece Budgetary Pricing

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